

# How electrons move?



Hall effect



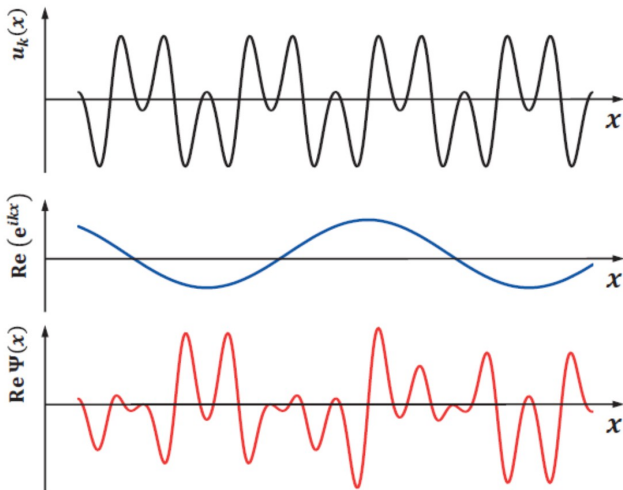
strontium titanate ( $\text{SrTiO}_3$ )



Marvin Cohen



Before we start,  
please take 5 minutes  
to fill in the evaluation form  
for this module



periodic part  $u_{nk}$

plane wave

Bloch wave

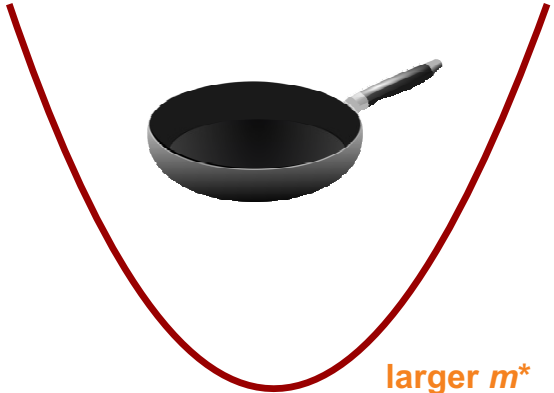
a hairpin

is lighter than

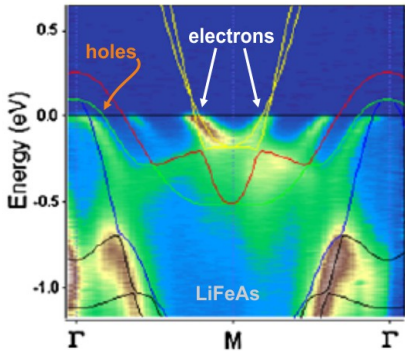
a frying pan



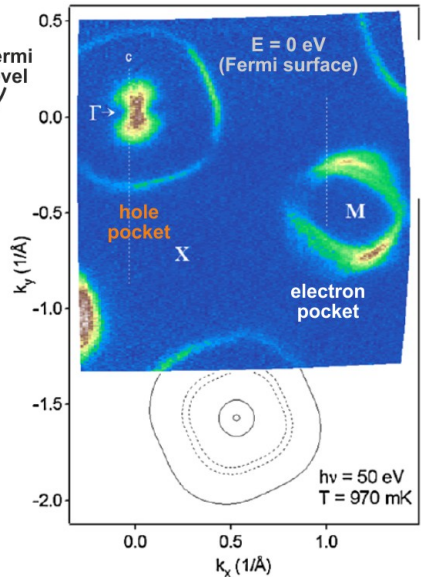
smaller  $m^*$



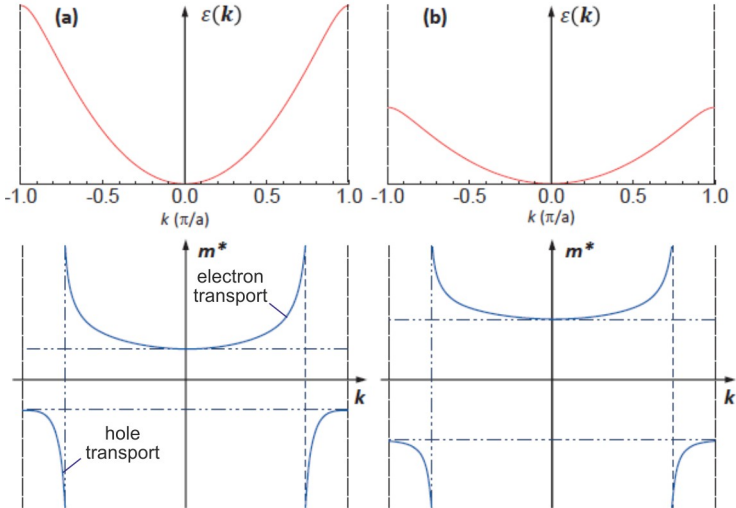
larger  $m^*$



Bands of different type may occur near the Fermi level



# Effective mass: positive vs. negative



Even single band may have hole and electron regions



Person

*Marvin Cohen*



Marvin Cohen  
(born 1935)

- 1953-1957: bachelor in Berkley, not accepted for master program
- 1958-1963: master and PhD in Chicago theory work based on electronic structure calculations for real materials
- 1963-1964: very short postdoc at Bell Labs
- since 1964: professor at Berkley
- 1960-70's: optical properties of semiconductors
- since 1970's: high-pressure transformations of solids
- 1980's: superconductors
- since 1990's: carbon allotropes, nanotubes





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# Pseudopotentials



replacing inner electrons  
with pseudopotential

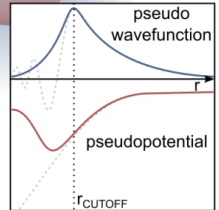
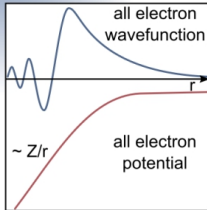
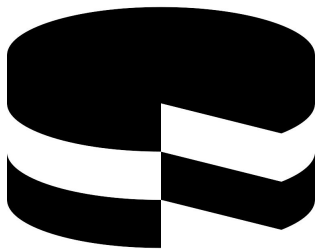


image by Edvin Fako  
(CC-BY-SA)

M.L. Cohen  
Phys. Scr. T1, 5 (1982)

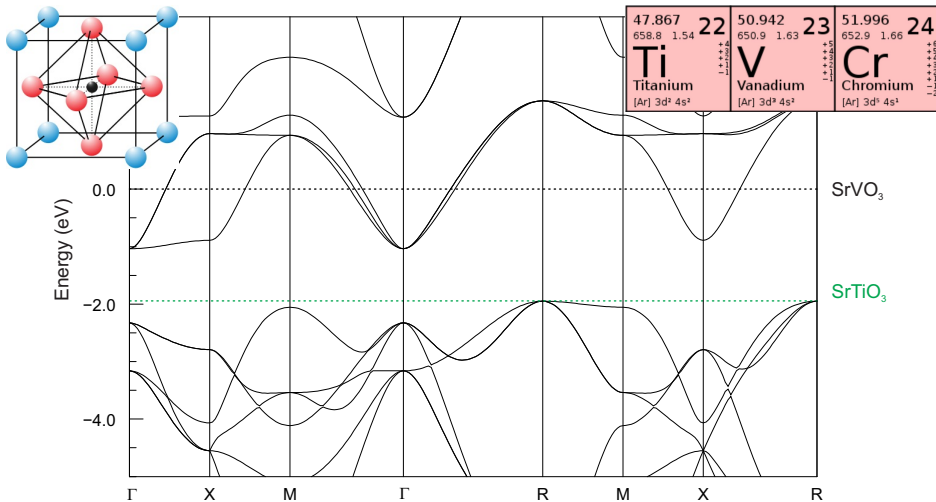
	lattice constant (Å)	cohesive energy (eV)	bulk modulus (Mbar)
<b>Si</b>			
Calc.	5.45	4.67	0.98
Expt.	5.43	4.63	0.99
% Diff.	0.4%	1%	-1%
<b>Ge</b>			
Calc.	5.66	4.02	0.73
Expt.	5.65	3.85	0.77
% Diff.	0.1%	4%	-5%



Material

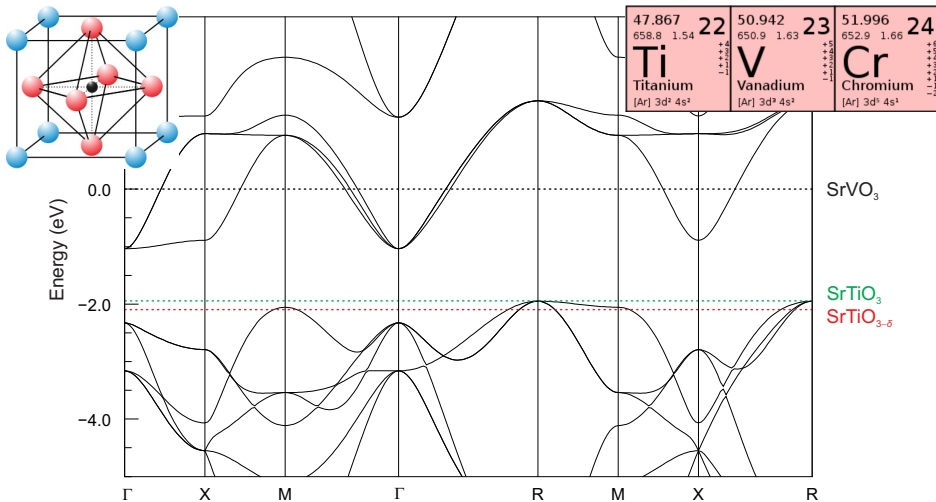
*strontium titanate ( $\text{SrTiO}_3$ )*

# Superconducting semiconductor



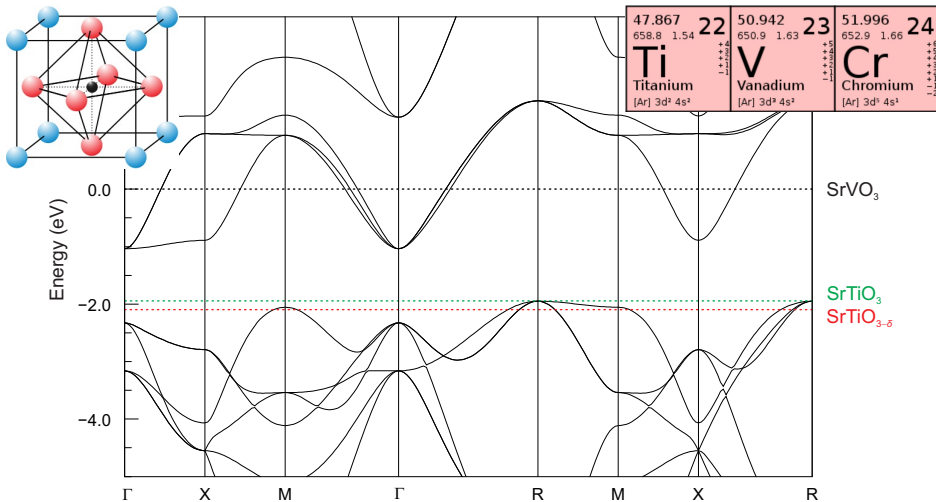
SrTiO<sub>3</sub> is mundane wide-gap semiconductor ( $\rho = 10^9 \Omega\cdot\text{cm}$ )

# Superconducting semiconductor



SrTiO<sub>3</sub> is mundane wide-gap semiconductor ( $\rho = 10^9 \Omega\cdot\text{cm}$ ),  
while SrTiO<sub>3-δ</sub> is **metallic** ( $\rho \sim 10 \text{ m}\Omega\cdot\text{cm}$ )

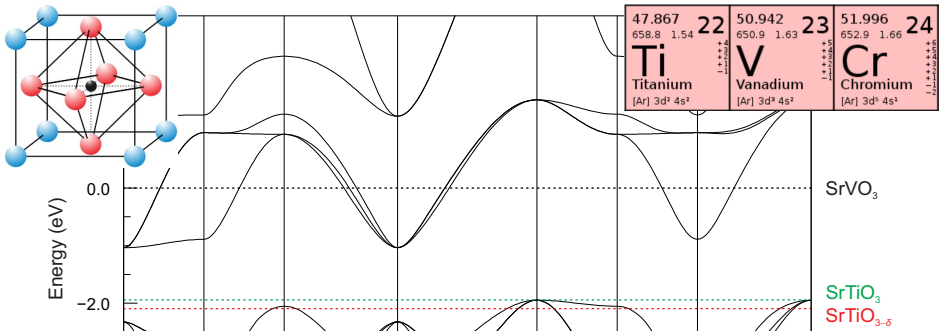
# Superconducting semiconductor



SrTiO<sub>3</sub> is mundane wide-gap semiconductor ( $\rho = 10^9 \Omega\cdot\text{cm}$ ),  
while SrTiO<sub>3- $\delta$</sub>  is **metallic** ( $\rho \sim 10 \text{ m}\Omega\cdot\text{cm}$ ), possibly superconducting



# Superconducting semiconductor



## PHYSICAL REVIEW LETTERS

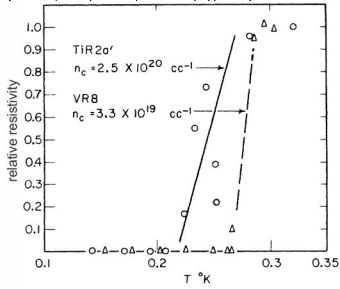
### SUPERCONDUCTIVITY IN SEMICONDUCTING SrTiO<sub>3</sub>

J. F. Schooley and W. R. Hosler  
National Bureau of Standards, Washington, D. C.

and

Marvin L. Cohen  
Bell Telephone Laboratories, Murray Hill, New Jersey  
(Received 6 March 1964)

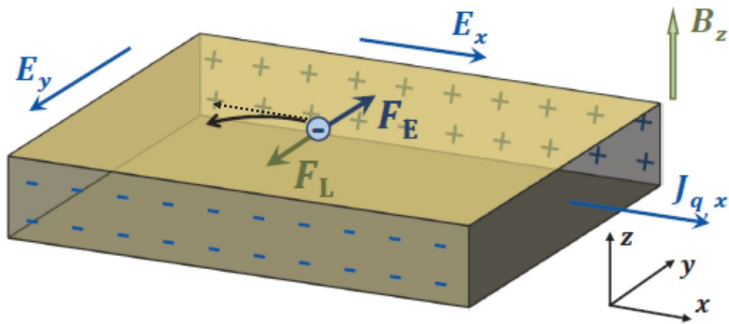
Vol. 12, Page 474





# Experimental technique

*Hall effect*



$$E_y = -\frac{B_z}{n_e e} j_x \quad \Rightarrow \quad R_H = \frac{E_y}{B_z j_x} = -\frac{1}{n_e e}$$

(direct measure of charge-carrier concentration)

# Hall magnetometry



Image credit: Mitchell Instrument (fair use)

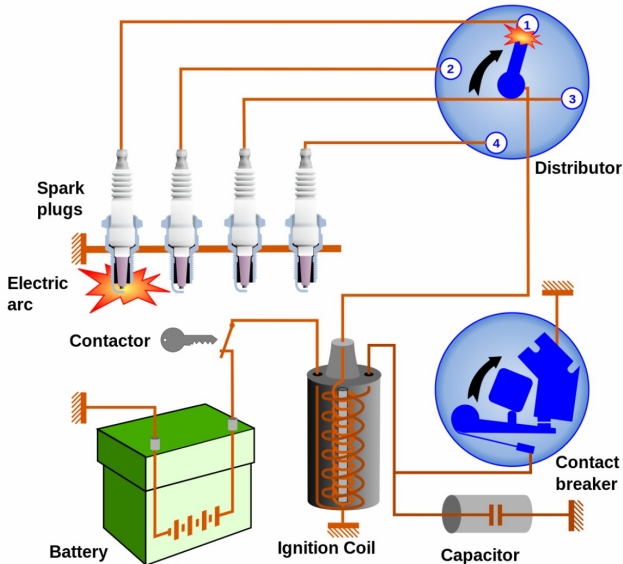


Image credit: Frédéric MICHEL and Rudolf Stricker (CC-BY-SA)

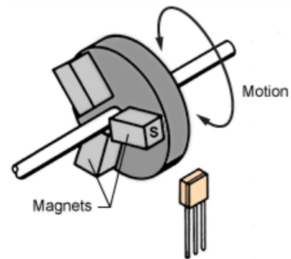
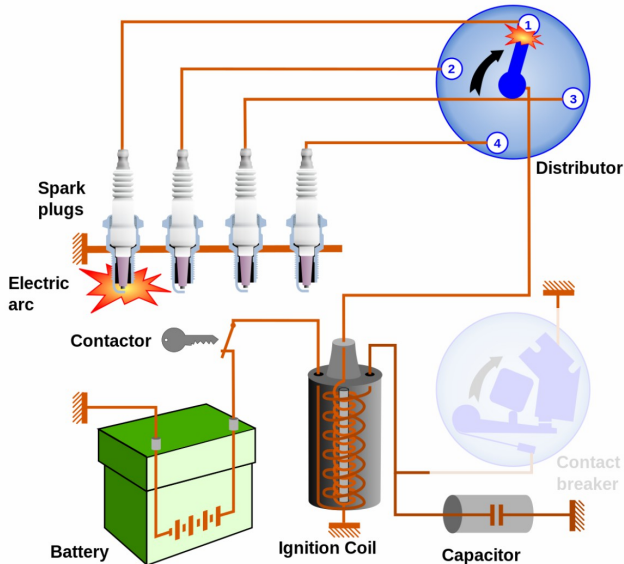
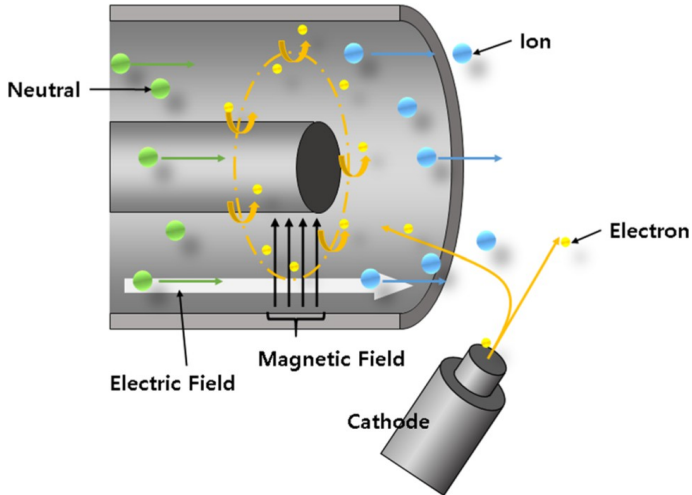


Image credit: Frédéric MICHEL and Vauxford (CC-BY-SA), Allegro Microsystems (fair use)



# Hall-effect thruster

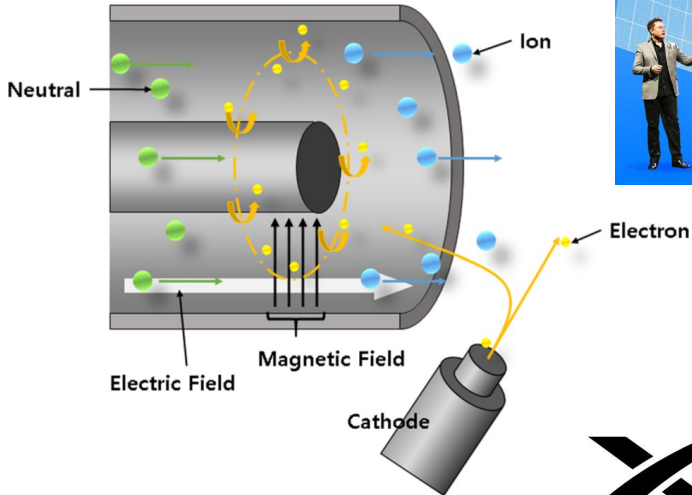


Image credit: Int. J. Aeronaut. Space Sci. 21, 1028 (2020) and Starlink

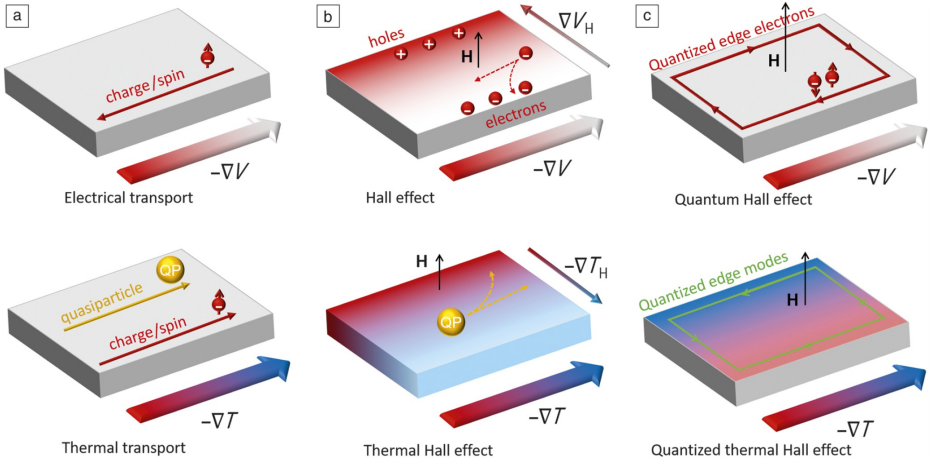


# Hall effect in simple metals

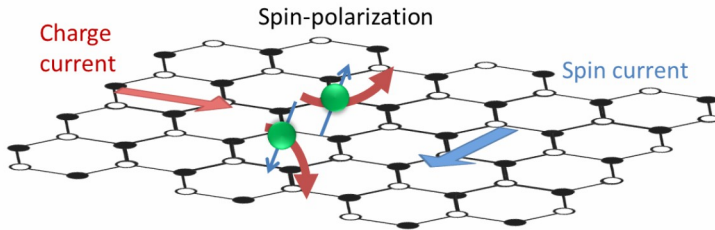
METAL	VALENCE	$-1/R_H nec$	
Li	1	0.8	electron carriers
Na	1	1.2	
K	1	1.1	
Rb	1	1.0	
Cs	1	0.9	
Cu	1	1.5	
Ag	1	1.3	
Au	1	1.5	
Be	2	-0.2	hole carriers
Mg	2	-0.4	
In	3	-0.3	
Al	3	-0.3	

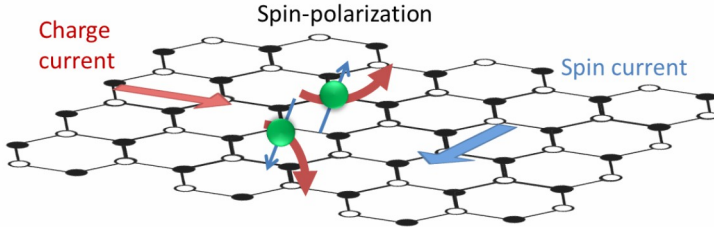
N.W. Ashcroft, N.D. Mermin, Solid State Physics

**N.B.**  $R_H$  values in the high-field limit; experimentally,  $R_H$  depends on the magnetic field!

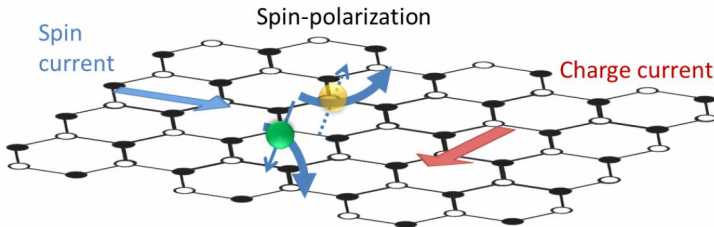


Signature of non-trivial features in electronic/magnetic structure  
occurs in metals, magnetic insulators...

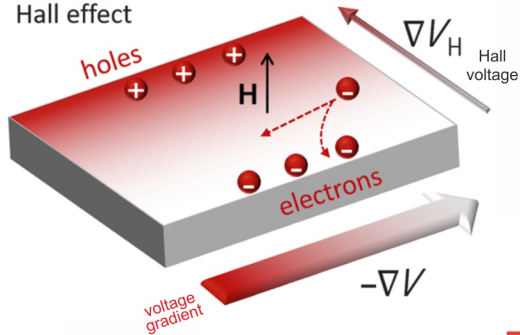




caused by spin-orbit coupling  
common in “heavy” metals (Os, Pt)



## Hall effect

same SrTiO<sub>3</sub>

$$\nu = 40 \frac{\mu\text{V}}{\text{T}\cdot\text{K}}$$

doped SrTiO<sub>3</sub> at 4.2 K  
 ( $n_e = 5.5 \cdot 10^{17} \text{ cm}^{-3}$ )

$$R_H \simeq 1000 \frac{\mu\text{V}\cdot\text{m}}{\text{T}\cdot\text{A}}$$

## Nernst effect

